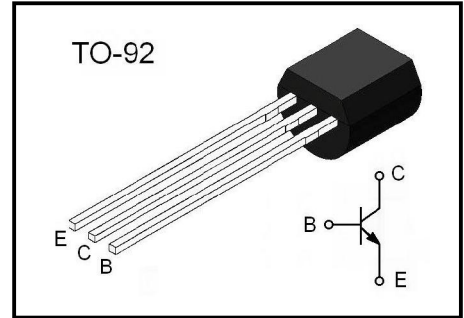


**NPN Plastic-Encapsulate Transistors**

Switching and Amplifier Applications



**Absolute Maximum Ratings (Ta=25°C)**

Parameter	Symbol	Value	Unit
Collector-Base Voltage	$BV_{CBO}$	50	V
Collector-Emitter Voltage	$BV_{CEO}$	45	V
Emitter-Base Voltage	$BV_{EBO}$	6	V
Collector Current	$I_C$	100	mA
Collector Power Dissipation	$P_C$	500	mW
Junction Temperature	$T_j$	150	°C
Storage Temperature	$T_{stg}$	-55~+150	°C

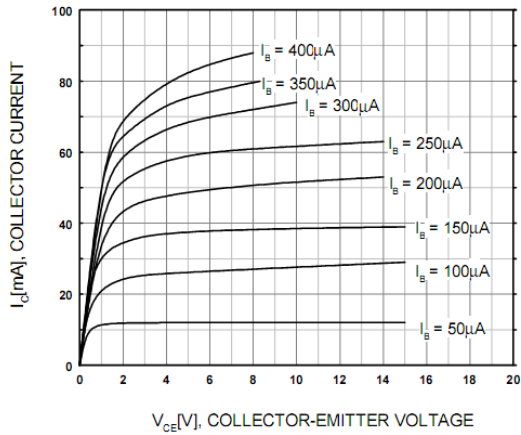
**ELECTRICAL CHARACTERISTICS (Ta=25°C)**

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$BV_{CBO}$	$I_C = 100\mu A, I_E = 0$	50			V
Collector-emitter breakdown voltage	$BV_{CEO}$	$I_C = 1mA, I_B = 0$	45			V
Emitter-base breakdown voltage	$BV_{EBO}$	$I_E = 100\mu A, I_C = 0$	6			V
Collector cut-off current	$I_{CBO}$	$V_{CB} = 50V, I_E = 0$			15	nA
Emitter cut-off current	$I_{EBO}$	$V_{EB} = 5V, I_C = 0$			15	nA
DC current gain	$h_{FE}$	$V_{CE} = 5V, I_C = 2mA$	120		800	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 10mA, I_B = 0.5mA$			0.2	V
		$I_C = 100mA, I_B = 5mA$			0.6	
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C = 10mA, I_B = 0.5mA$			0.83	V
		$I_C = 100mA, I_B = 5mA$			1.05	
Base-emitter saturation voltage	$V_{BE(on)}$	$V_{CE} = 5V, I_C = 2mA$			0.7	V
Transition frequency	$f_T$	$V_{CE} = 5V, I_C = 10mA$	150			MHz
Collector output capacitance	$C_{ob}$	$V_{CB} = -10V, I_E = 0, f = 1MHz$		3.5		pF

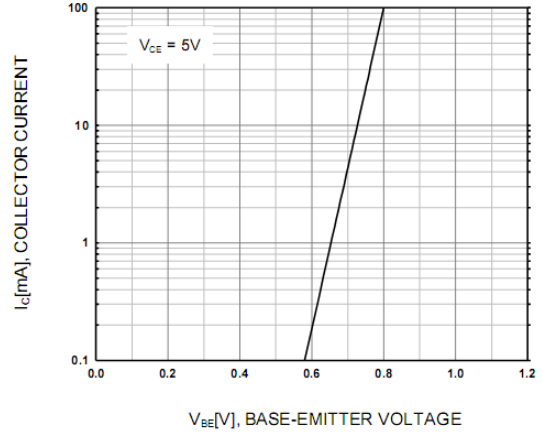
**hFE Classification**

Classification	BC237-A	BC237-B	BC237-C
Range	120~220	180~460	380~800

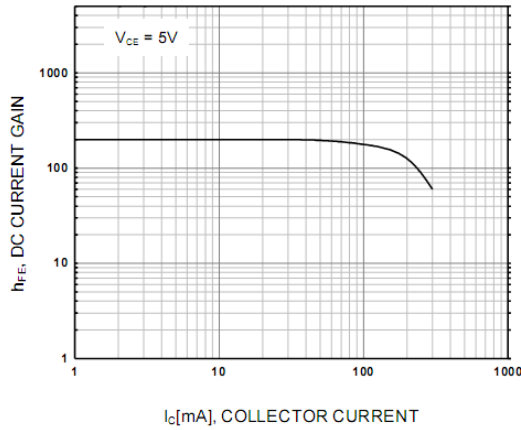
Typical Characteristics



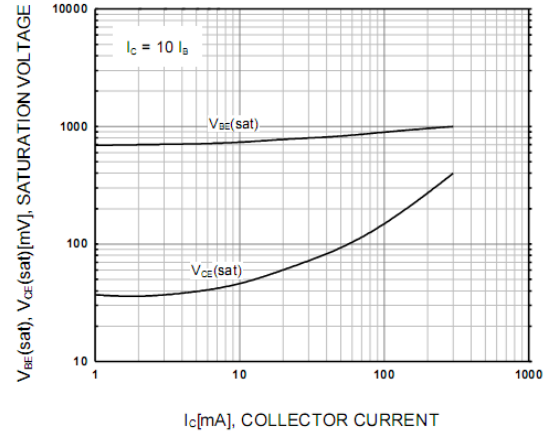
**Figure 1. Static Characteristic**



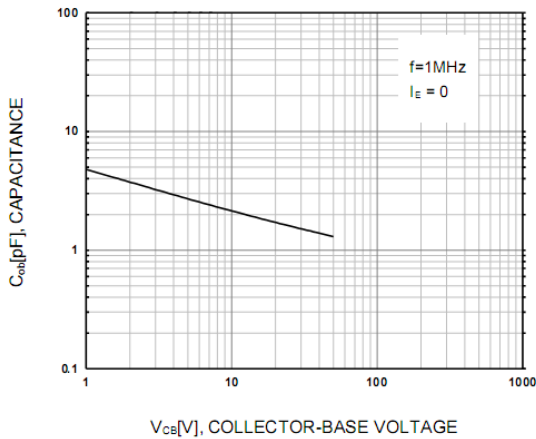
**Figure 2. Transfer Characteristic**



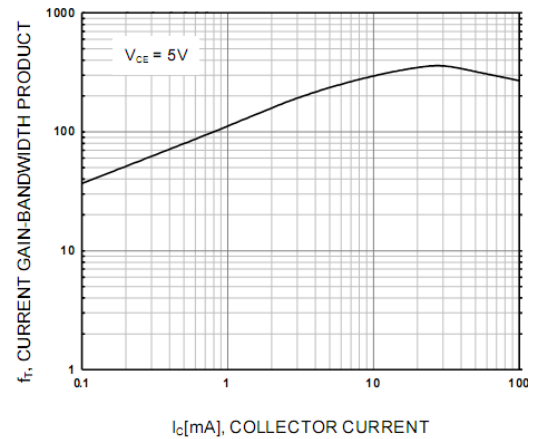
**Figure 3. DC current Gain**



**Figure 4. Saturation Voltage**



**Figure 5. Output Capacitance**



**Figure 6. Current Gain Bandwidth Product**

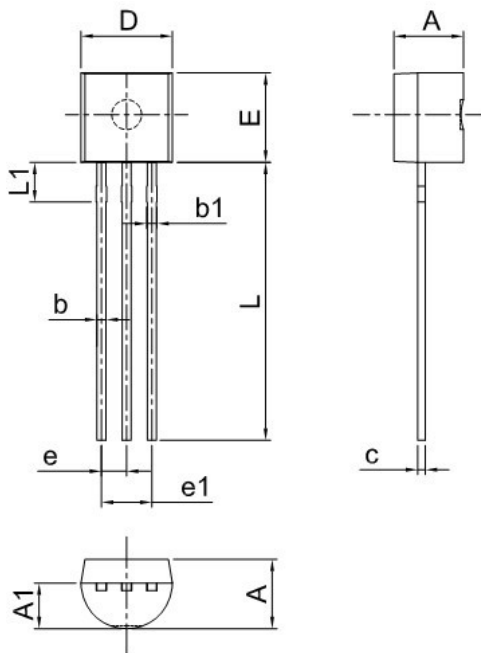
**Ordering information**

Package	Packing Description	Base Quantity
TO-92	Bulk	1000pcs/Bag
	Tape	2000pcs/Box

**Package Dimensions**

**TO-92**

Dim	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	3.30	3.70	0.130	0.146
A1	2.30	2.70	0.091	0.106
b	0.40	0.50	0.016	0.020
b1	0.50	0.70	0.020	0.028
c	0.35	0.45	0.014	0.018
D	4.45	4.70	0.175	0.185
E	4.40	4.65	0.173	0.183
e	1.17	1.37	0.046	0.054
e1	2.34	2.64	0.092	0.104
L	13.50	14.50	0.531	0.571
L1	1.80	2.20	0.071	0.087



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